NSN 5961-01-331-5990

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-331-5990 **Inclosure Material:** Plastic **Overall Length:** 24.0 millimeters **Terminal Length:** 3.0 millimeters **Overall Height:** 9.0 millimeters **Overall Width:** 3.5 millimeters **Component Name And Quantity:** 8 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 40.0 reverse voltage, peak all semiconductor device diode and 40.0 reverse voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 4.00 amperes forward current, average preset all semiconductor device diode and 300.00 milliamperes source cutoff current absolute all semiconductor device diode **Special Features:** Common anode; all semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 9 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No